

NOT RECOMMENDED FOR NEW DESIGN CONTACT US



ZXMP2120G4

200V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	Rds(on)	I _D T _A = +25°C
-200V	25Ω @ V _{GS} = 10V	-200mA

Description and Applications

This new generation trench MOSFET features a unique structure combining the benefits of low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Active clamping of primary side MOSFETs in 48 Volt DC-DC converters

Features and Benefits

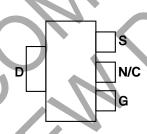
- High Voltage
- Low On-Resistance
- Fast Switching Speed
- Low Gate Drive
- Low Threshold
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

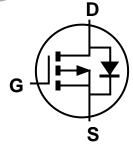
- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (3)
- Weight: 0.112 grams (Approximate)







Pin Out - Top View



Equivalent Circuit

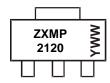
Ordering Information (Note 4)

Part Number	Dankaga	Packing	
Fait Number	Package	Qty.	Carrier
ZXMP2120G4TA	SOT223 (Type DN)	1,000	Tape & Reel
ZXMP2120G4TC	SOT223 (Type DN)	4,000	Tape & Reel

Notes

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



ZXMP2120 = Product Type Marking Code YWW = Date Code Marking Y or Y = Last Digit of Year (ex: 2 = 2022) WW or WW = Week Code (01 to 53)



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	VDSS	-200	V
Gate-Source Voltage	V_{GSS}	±20	V
Continuous Drain Current (V _{GS} = 10V; T _A = +25°C) (Note 5)	ID	-200	mA
Pulsed Drain Current (Note 6)	I _{DM}	-1	А
Pulsed Source Current (Body Diode) (Note 6)	Ism	-1	A

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation at T _A = +25°C (Note 5) Linear Derating Factor	P _D	2.0	W mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	Reja	62.5	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

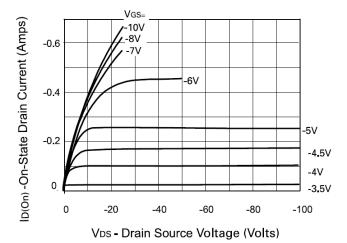
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BVpss	-200	. –	1	V	$V_{GS} = 0V$, $I_D = -1mA$	
Zero Gate Voltage Drain Current	IDSS		-	-10 -100	μA	V _{DS} = -200V, V _{GS} = 0V V _{DS} = -160V, V _{GS} = 0V, T = +125°C	
Gate-Source Leakage	IGSS	_		20	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	VGS(TH)	-1.5	_	-3.5	V	$V_{DS} = V_{GS}$, $I_{D} = -1mA$	
Static Drain-Source On-Resistance (Note 7)	R _{DS(ON)}	—		25	Ω	$V_{GS} = -10V, I_D = -150mA$	
Forward Transconductance (Notes 7 & 8)	gfs	50		-	mS	$V_{DS} = -25V, I_{D} = -150mA$	
On-State Drain Current (Note 7)	I _D (ON)	-300	_	_	mA	V _{DS} = -25V, V _{GS} = -10V	
DYNAMIC CHARACTERISTICS	DYNAMIC CHARACTERISTICS						
Input Capacitance (Note 8)	Ciss	_	_	100	pF	V _{DS} = -25V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance (Note 8)	Coss		_	25	pF		
Reverse Transfer Capacitance (Note 8)	Crss	· —	_	7	pF		
Turn-On Delay Time (Notes 8 & 9)	t _D (ON)	_	_	7	ns	V _{DD} = -25V, I _D = -150mA	
Turn-On Rise Time (Notes 8 & 9)	tr	_	_	15	ns		
Turn-Off Delay Time (Notes 8 & 9)	tD(OFF)	_	_	12	ns		
Turn-Off Fall Time (Notes 8 & 9)	t _F	_	_	15	ns		

Notes:

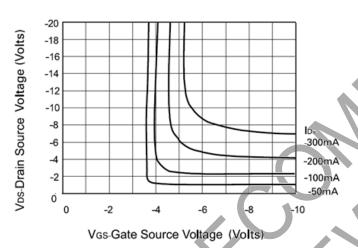
- 5. For a device surface mounted on 25mm × 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 6. Repetitive rating pulse width limited by maximum junction temperature. Refer to Transient Thermal Impedance graph.
 7. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

- 8. Sample test.
 9. Switching characteristics are independent of operating junction temperature.

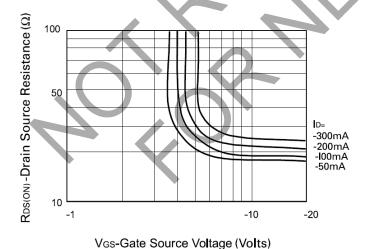




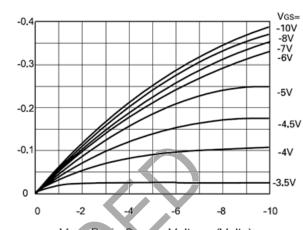




Voltage Saturation Characteristics

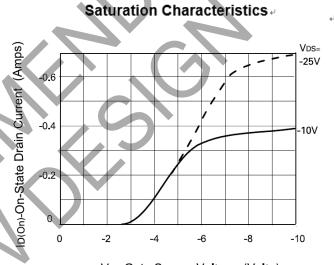


On-resistance vs gate-source voltage



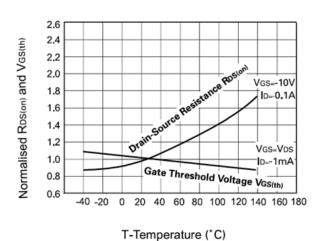
ID(On) -On-State Drain Current (Amps)

V_Ds - Drain Source Voltage (Volts) ⊬



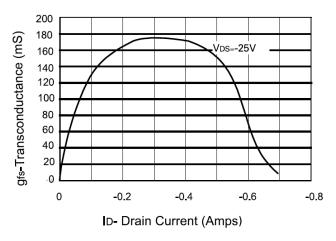
VGS-Gate Source Voltage (Volts)

Transfer Characteristics

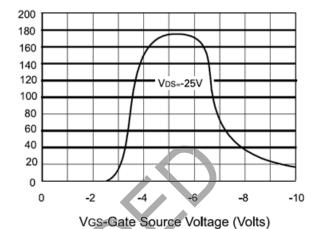


Normalised RDS(on) and VGS(th) vs Temperature



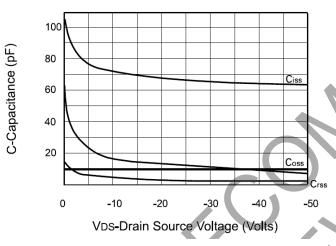


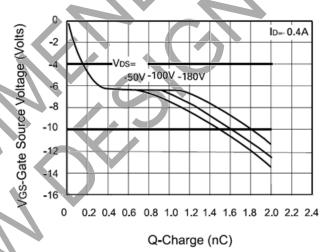
gfs-Transconductance (mS)



Transconductance v drain current

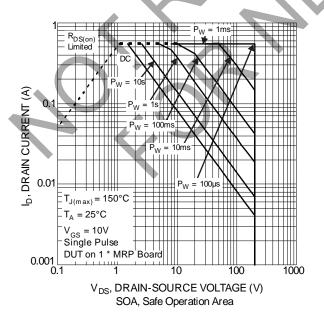
Transconductance v gate-source voltage



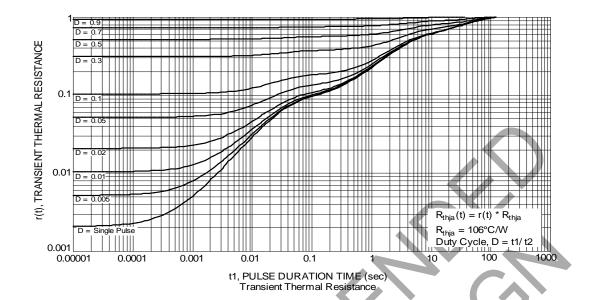


Capacitance v drain-source voltage

Gate charge v gate-source voltage





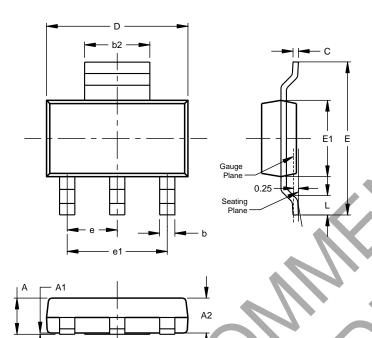




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

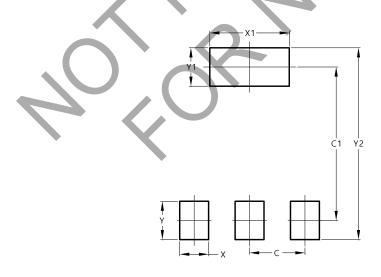


SOT223 (Type DN)				
Dim	Min	Max	Тур	
Α	-	1.70		
A1	0.01	0.15		
A2	1.50	1.68	1.60	
b	0.60	0.80	0.70	
b2	2.90	3.10		
С	0.20	0.32		
D	6.30	6.70		
E	6.70	7.30		
E	3.30	3.70		
Ð	1		2.30	
e1) !		4.60	
7	0.85			
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

October 2022



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